





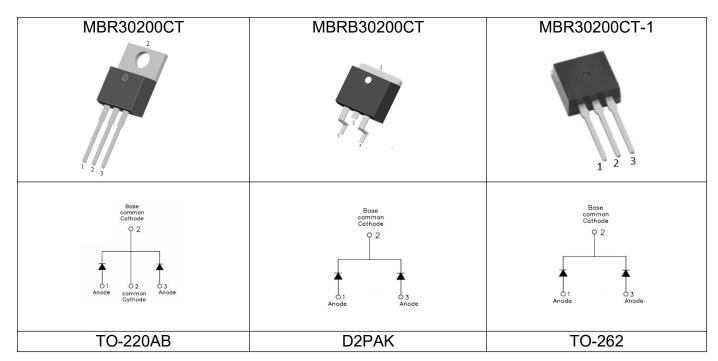
MBR30200CT/MBRB30200CT-MBR30200CT-1 SCHOTTKY RECTIFIER

Features

- 150 °C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|--|--|---|-------------------------------|-------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | - | 200 | V |
| Average Rectified Forward Current | I _{F (AV)} | 50% duty cycle @Tc=133°C, rectangular wave form | 15(Per Leg) 30(Per Device) | Α |
| Peak Repetitive Forward Current(Per Leg) | I _{FRM} | Rated V _R square wave, 20KHz T _C = 133°C | 20 | А |
| Peak One Cycle Non-Repetitive Surge Current(Per Leg) | I _{FSM} | 8.3ms, Half Sine pulse | 200 | Α |

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Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|-------------------------------|-----------------|---|--------|--------|-------|
| Forward Voltage Drop | V _{F1} | @ 15 A, Pulse, T _J = 25 °C | 0.85 | 0.90 | V |
| (Per Leg)* | V _{F2} | @ 15 A, Pulse, T _J = 125 °C | 0.72 | 0.75 | V |
| Reverse Current (Per Leg)* | I _{R1} | $@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$ | 0.0001 | 1.0 | mA |
| | I _{R2} | $@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$ | 0.1 | 6.0 | mA |
| Junction Capacitance(Per Leg) | Ст | $@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$ | 200 | 400 | pF |
| Voltage Rate of Change | dv/dt | - | - | 10,000 | V/μs |

 $^{^*\,}$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%

Thermal-Mechanical Specifications:

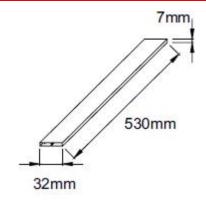
| Characteristics | Symbol | Condition | Specification | Units |
|--|------------------------------------|--------------------------------------|---------------|-------|
| Junction Temperature | TJ | - | -55 to +150 | °C |
| Storage Temperature | T _{stg} | - | -55 to +150 | °C |
| Typical Thermal Resistance Junction to Case | R _θ JC | DC operation | 1.5 | °C/W |
| Typical Thermal Resistance Junction to Ambient | $R_{	heta JA}$ | DC operation | 50 | °C/W |
| Typical Thermal Resistance, Case to Heat Sink | R _{0CS} | Mounting surface, smooth and greased | 0.50 | °C/W |
| Case Style | TO-220AB D ² PAK TO-262 | | | |

Tube Specification

| Device | Package | Weight | Shipping |
|--------------|----------|--------|---------------|
| MBR30200CT | TO-220AB | 1.8g | 50pcs / tube |
| MBRB30200CT | D² PAK | 1.85g | 800pcs / reel |
| MBR30200CT-1 | TO-262 | 1.85g | 50pcs / tube |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification(TO-220AB/TO-262)



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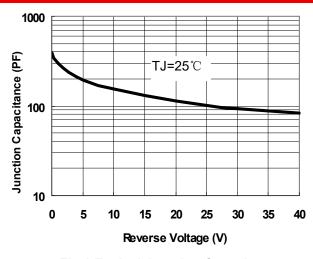
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Ratings and Characteristics Curves



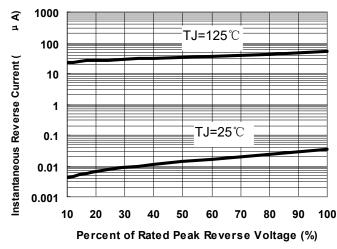


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

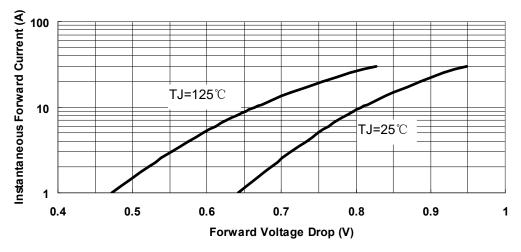


Fig.3-Typical Instantaneous Forward Voltage Characteristics

Marking Diagram Where XXXXX is YYWWL MBR30200CT-1 **MBR** = Device Type = Package type MBR30200CT MBRB30200CT 0 SSG XXXXX 30 = Forward Current (30A) XXXXX 200 = Reverse Voltage (200V) CT-1 = Configuration SSG = SSG = Year WW = Week = Lot Number Cautions: Molding resin Epoxy resin UL:94V-0

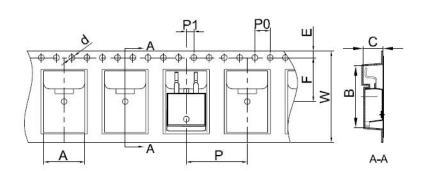
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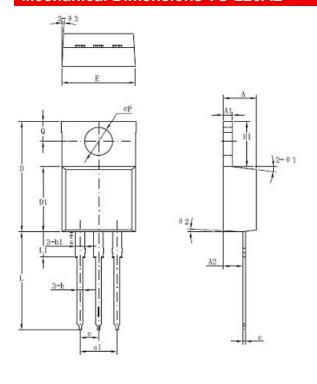


Carrier Tape Specification D2PAK



| Symbol | Millimeters | | |
|--------|-------------|-------|--|
| | Min. | Max. | |
| Α | 10.70 | 10.90 | |
| В | 16.03 | 16.23 | |
| С | 5.11 | 5.31 | |
| d | 1.45 | 1.65 | |
| E | 1.65 | 1.85 | |
| F | 11.40 | 11.60 | |
| P0 | 3.90 | 4.10 | |
| Р | 15.90 | 16.10 | |
| P1 | 1.90 | 2.10 | |
| W | 23.90 | 24.30 | |

Mechanical Dimensions TO-220AB



| Symbol | Millimeters | | | |
|--------|-------------|---------|-------|--|
| | Min. | Typical | Max. | |
| Α | 4.42 | 4.57 | 4.72 | |
| A1 | 1.17 | 1.27 | 1.37 | |
| A2 | 2.52 | 2.69 | 2.89 | |
| b | 0.71 | 0.81 | 0.96 | |
| b1 | 1.17 | 1.27 | 1.37 | |
| С | 0.31 | 0.38 | 0.61 | |
| D | 14.94 | 15.24 | 15.54 | |
| D1 | 8.85 | 9.00 | 9.15 | |
| Е | 10.01 | 10.16 | 10.31 | |
| е | | 2.54 | | |
| e1 | 4.98 | 5.06 | 5.18 | |
| H1 | 6.04 | 6.24 | 6.44 | |
| L | 12.7 | 13.56 | 13.80 | |
| L1 | 3.56 | 3.5 | 3.96 | |
| ФР | 3.74 | 3.84 | 4.04 | |
| Q | 2.54 | 2.74 | 2.94 | |
| Θ1 | | 7° | | |
| Θ2 | | 3° | | |
| Θ3 | | 4° | | |

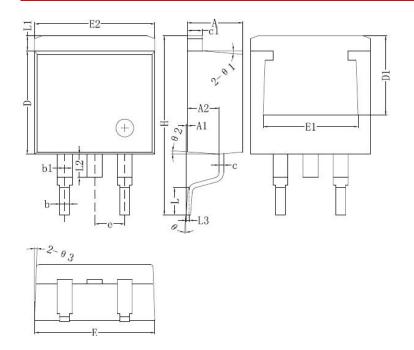
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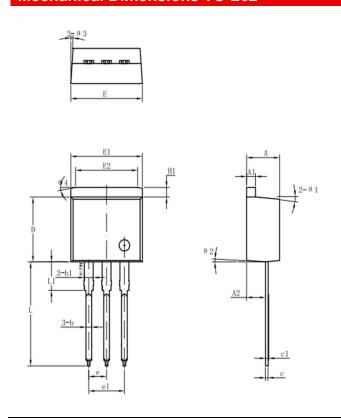


Mechanical Dimensions D²PAK



| Symbol | Millimeters | | | |
|--------|-------------|---------|-------|--|
| | Min. | Typical | Max. | |
| Α | 4.47 | 4.70 | 4.85 | |
| A1 | 0 | 0.10 | 0.25 | |
| A2 | 2.59 | 2.69 | 2.89 | |
| b | 0.71 | 0.81 | 0.96 | |
| b1 | 1.17 | 1.27 | 1.37 | |
| С | 0.31 | 0.38 | 0.61 | |
| c1 | 1.17 | 1.27 | 1.37 | |
| D | 8.50 | 8.70 | 8.90 | |
| D1 | 6.40 | | | |
| E | 10.01 | 10.16 | 10.31 | |
| E1 | 7.6 | | | |
| E2 | 9.98 | 10.08 | 10.31 | |
| е | | 2.54 | | |
| Н | 14.6 | 15.1 | 15.6 | |
| L | 2.00 | 2.30 | 2.74 | |
| L1 | 1.12 | 1.27 | 1.42 | |
| L2 | 1.30 | | 2.20 | |
| L3 | | 0.25BSC | | |
| е | 0 | - | 8° | |
| e1 | | 5° | | |
| e2 | | 4° | | |
| e3 | | 4° | | |

Mechanical Dimensions TO-262



| Cumbal | Millimeters | | | |
|--------|-------------|---------|-------|--|
| Symbol | Min. | Typical | Max. | |
| Α | 4.55 | 4.70 | 4.85 | |
| A1 | 0 | 0.10 | 0.25 | |
| A2 | 2.59 | 2.69 | 2.89 | |
| b | 0.71 | 0.81 | 0.96 | |
| b1 | | 1.27 | | |
| С | 0.36 | 0.38 | 0.61 | |
| c1 | 1.17 | 1.27 | 1.37 | |
| D | 8.55 | 8.70 | 8.85 | |
| D1 | 6.40 | | | |
| E | 10.01 | 10.16 | 10.31 | |
| E1 | 7.6 | | | |
| E2 | 9.98 | 10.08 | 10.18 | |
| е | | 2.54 | | |
| Н | 14.6 | 15.1 | 15.6 | |
| L | 2.00 | 2.30 | 2.70 | |
| L1 | 1.17 | 1.27 | 1.40 | |
| L2 | | | 2.20 | |
| L3 | | 0.25BSC | | |
| е | 0 | - | 8° | |
| e1 | | 5° | | |
| e2 | | 4° | | |
| e3 | | 4° | | |

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MBR30200CT MBRB30200CT MBR30200CT-1

Technical Data Data Sheet N0039, Rev. A





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